Technical Data Data Sheet N1056, Rev. - Green Products

# 66CNQ0200 SCHOTTKY RECTIFIER

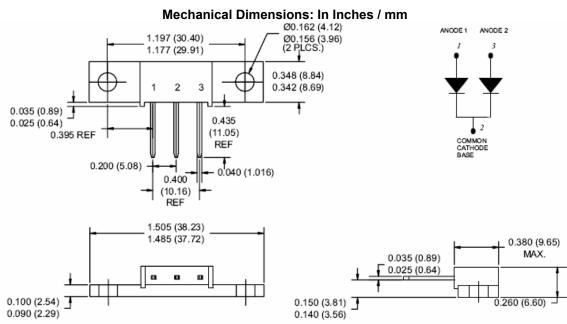
## **Applications:**

- · Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

#### Features:

- 175°C T<sub>J</sub> operation
- Center tap module
- Very Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- . Guard ring for enhanced ruggedness and long term reliability
- Low profile, high current package
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request





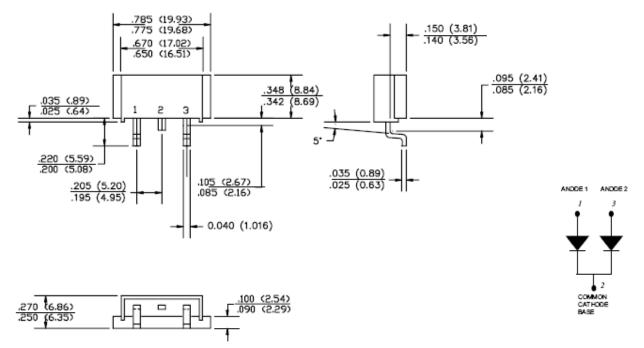
<sup>•</sup> Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 🗏 (86) 25-87123907 •

PRM3

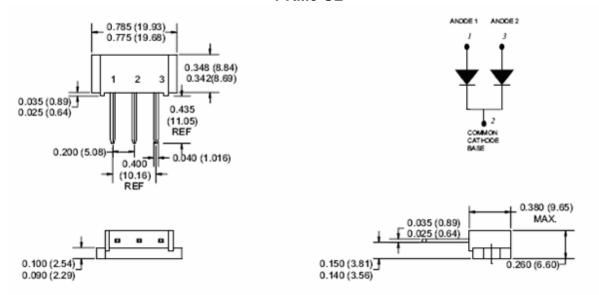
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66CNQ200

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### PRM3-SL



### PRM3-SM

## MARKING, MOLDING RESIN

Marking for 66CNQ200/SL/SM, 1<sup>st</sup> row SS YYWWL, 2<sup>nd</sup> row 66CNQ200/SL/SM, 3<sup>rd</sup> row 1 2 3 (pin) Where YY is the manufacture year WW is the manufacture week code L is the wafer's Lot Number

Molding resin

Epoxy resin UL: 94V-0

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# **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	200	V
Max. Average Forward	I <sub>F(AV)</sub>	50% duty cycle @T <sub>C</sub> =155°C, rectangular wave form	60	А
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse	708	А

## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop (per leg) *	$V_{F1}$	@ 30A, Pulse, T <sub>J</sub> = 25 °C	0.92	V
	$V_{F2}$	@ 30A, Pulse, T <sub>J</sub> = 125 °C	0.72	V
Max. Reverse Current (per leg) *	I <sub>R1</sub>	$@V_R = \text{rated } V_R T_J = 25  ^{\circ}\text{C}$	1.5	mA
	I <sub>R2</sub>	$@V_R = \text{rated } V_R T_J = 125  ^{\circ}\text{C}$	21	mA
Max. Junction Capacitance (per leg)	C <sub>T</sub>	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	900	pF
Typical Series Inductance (per leg)	L <sub>S</sub>	Measured lead to lead 5 mm from package body	6.0	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs

<sup>\*</sup> Pulse Width < 300µs, Duty Cycle <2%

# **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	$T_J$	-	-55 to +175	°C
Max. Storage Temperature	T <sub>stg</sub>	-	-55 to +175	°C
Maximum Thermal Resistance Junction to Case (per leg)	$R_{ ext{ heta}JC}$	DC operation	0.85	°C/W
Maximum Thermal Resistance Junction to Case (per package)	$R_{ heta JC}$	DC operation	0.42	°C/W
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.30	°C/W
Mounting Torque	Тм	-	40(min)	Kg-cm
			58(max)	
Approximate Weight	wt	-	7.8	g
Case Style	PRM3 PRM3-SL PRM3-SM			

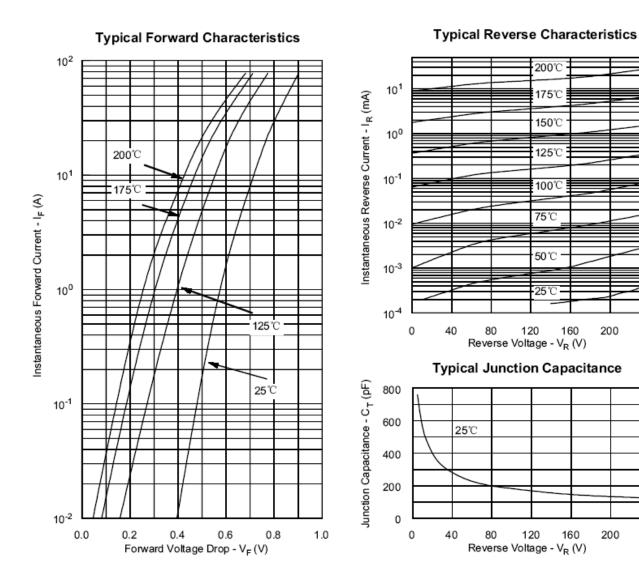




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